

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L2	2510	257/690	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/23 13:16
L3	4814	257/778	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/23 14:40
L4	3	(semiconductor adj element) and (first adj substrate) and (first adj internal) and (first adj external) and (second adj substrate) and (second adj substrate) and (second adj internal)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/23 14:44
L5	2	(semiconductor adj element) and (first adj substrate) and (first adj internal) and (first adj external) and (second adj substrate) and (second adj substrate) and (second adj internal)	US-PGPUB	OR	ON	2005/11/23 14:44
S1	8621	yokoi.in.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/23 10:40
S2	99	S1 and tetsuya	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/23 11:00
S5	2506	257/700	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/11/23 11:03

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L5	2	(semiconductor adj element) and (first adj substrate) and (first adj internal) and (first adj external) and (second adj substrate) and (second adj substrate) and (second adj internal)	US-PGPUB	OR	ON	2005/11/23 14:44